

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74VCX162373FT

## LOW-VOLTAGE 16-BIT D-TYPE LATCH WITH 3.6 V TOLERANT INPUTS AND OUTPUTS

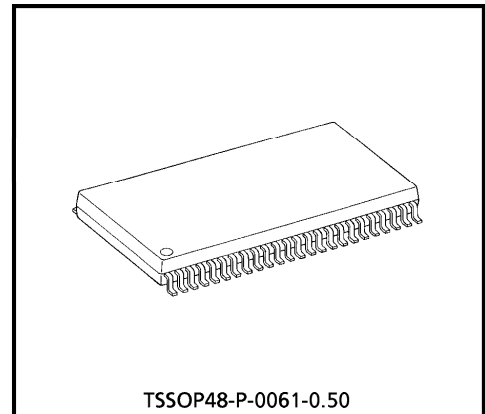
The TC74VCX162373FT is a high performance CMOS 16-bit D-TYPE LATCH. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6V.

This 16-bit D-type latch is controlled by a latch enable input (LE) and a output enable input ( $\overline{OE}$ ) which are common to each byte. It can be used as two 8-bit latches or one 16-bit latch. When the  $\overline{OE}$  input is high, the outputs are in a high impedance state.

The 26- $\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.



TSSOP48-P-0061-0.50  
Weight : 0.25 g (Typ.)

### PIN CONNECTION

$\overline{OE}$	1	48	1LE
1Q1	2	47	1D1
1Q2	3	46	1D2
GND	4	45	GND
1Q3	5	44	1D3
1Q4	6	43	1D4
VCC	7	42	VCC
1Q5	8	41	1D5
1Q6	9	40	1D6
GND	10	39	GND
1Q7	11	38	1D7
1Q8	12	37	1D8
2Q1	13	36	2D1
2Q2	14	35	2D2
GND	15	34	GND
2Q3	16	33	2D3
2Q4	17	32	2D4
VCC	18	31	VCC
2Q5	19	30	2D5
2Q6	20	29	2D6
GND	21	28	GND
2Q7	22	27	2D7
2Q8	23	26	2D8
$\overline{2OE}$	24	25	2LE

(TOP VIEW)

### FEATURES

- 26- $\Omega$  Series Resistors on Outputs.
- LowVoltage Operation :  $V_{CC} = 1.8\sim 3.6\text{ V}$
- High Speed Operation :  $t_{pd} = 3.3\text{ ns (max) at } V_{CC} = 3.0\sim 3.6\text{ V}$   
 :  $t_{pd} = 4.5\text{ ns (max) at } V_{CC} = 2.3\sim 2.7\text{ V}$   
 :  $t_{pd} = 5.8\text{ ns (max) at } V_{CC} = 1.8\text{ V}$
- 3.6 V Tolerant inputs and outputs.
- Output Current :  $I_{OH}/I_{OL} = \pm 12\text{ mA (min) at } V_{CC} = 3.0\text{ V}$   
 :  $I_{OH}/I_{OL} = \pm 8\text{ mA (min) at } V_{CC} = 2.3\text{ V}$   
 :  $I_{OH}/I_{OL} = \pm 4\text{ mA (min) at } V_{CC} = 1.8\text{ V}$
- Latch-up Performance :  $\pm 300\text{ mA}$
- ESD Performance : Human Body Model  $> \pm 2000\text{ V}$   
 : Machine Model  $> 200\text{ V}$
- Package : TSSOP  
 (Thin Shrink Small Outline Package)
- Power Down Protection is provided on all inputs and outputs.
- Supports live insertion / withdrawal (Note 1)

(Note 1) : To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

980910EBA2

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

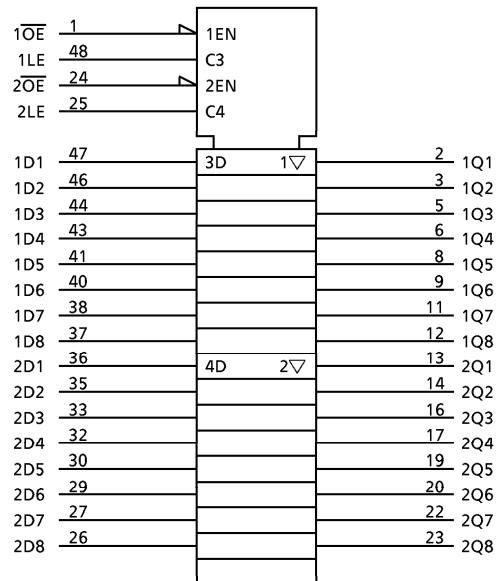
**TRUTH TABLE**

INPUT			OUTPUT
1OE	1LE	1D1-1D8	1Q1-1Q8
H	X	X	Z
L	L	X	Qn
L	H	L	L
L	H	H	H

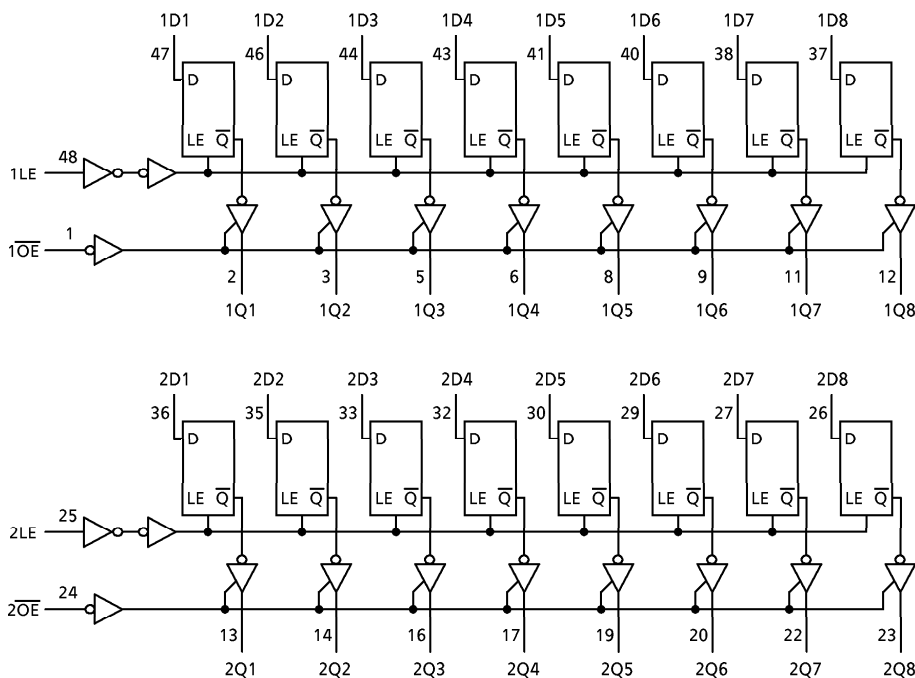
INPUT			OUTPUT
2OE	2LE	2D1-2D8	2Q1-2Q8
H	X	X	Z
L	L	X	Qn
L	H	L	L
L	H	H	H

X : Don't Care  
 Z : High impedance  
 Qn : Q outputs are latched at the time when the LE input is taken to a low logic level.

**IEC LOGIC SYMBOL**



**SYSTEM DIAGRAM**



980910EBA2'

- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

## MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	$V_{CC}$	-0.5~4.6	V
DC Input Voltage	$V_{IN}$	-0.5~4.6	V
DC Output Voltage	$V_{OUT}$	-0.5~4.6 (Note 1)	V
		-0.5~ $V_{CC}$ + 0.5 (Note 2)	
Input Diode Current	$I_{IK}$	-50	mA
Output Diode Current	$I_{OK}$	±50 (Note 3)	mA
DC Output Current	$I_{OUT}$	±50	mA
Power Dissipation	$P_D$	400	mW
DC $V_{CC}$ / Ground Current Per Supply Pin	$I_{CC} / I_{GND}$	±100	mA
Storage Temperature	$T_{stg}$	-65~150	°C

(Note 1) : Off-State

(Note 2) : High or Low State.  $I_{OUT}$  absolute maximum rating must be observed.

(Note 3) :  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## RECOMMENDED OPERATING RANGE

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	$V_{CC}$	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	$V_{IN}$	-0.3~3.6	V
Output Voltage	$V_{OUT}$	0~3.6 (Note 5)	V
		0~ $V_{CC}$ (Note 6)	
Output Current	$I_{OH} / I_{OL}$	±12 (Note 7)	mA
		±8 (Note 8)	
		±4 (Note 9)	
Operating Temperature	$T_{opr}$	-40~85	°C
Input Rise And Fall Time	$dt/dv$	0~10 (Note 10)	ns/V

(Note 4) : Data Retention Only

(Note 5) : Off-State

(Note 6) : High or Low State

(Note 7) :  $V_{CC} = 3.0\sim 3.6$  V

(Note 8) :  $V_{CC} = 2.3\sim 2.7$  V

(Note 9) :  $V_{CC} = 1.8$  V

(Note 10) :  $V_{IN} = 0.8\sim 2.0$  V,  $V_{CC} = 3.0$  V

**ELECTRICAL CHARACTERISTICS**

DC characteristics (Ta = -40~85°C, 2.7 V < VCC ≤ 3.6 V)

PARAMETER		SYMBOL	TEST CONDITION	VCC (V)	MIN	MAX	UNIT	
Input Voltage	"H" Level	V <sub>IH</sub>		2.7~3.6	2.0	—	V	
	"L" Level	V <sub>IL</sub>		2.7~3.6	—	0.8		
Output Voltage	"H" Level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.7~3.6	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -6 mA	2.7	2.2	—	
				I <sub>OH</sub> = -8 mA	3.0	2.4	—	
				I <sub>OH</sub> = -12 mA	3.0	2.2	—	
	"L" Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7~3.6	—	0.2	
				I <sub>OL</sub> = 6 mA	2.7	—	0.4	
				I <sub>OL</sub> = 8 mA	3.0	—	0.55	
				I <sub>OL</sub> = 12 mA	3.0	—	0.8	
Input Leakage Current		I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6 V	2.7~3.6	—	± 5.0	μA	
3-State Output Off-State Current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~3.6 V	2.7~3.6	—	± 10.0	μA	
Power Off Leakage Current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6 V	0	—	10.0	μA	
Quiescent Supply Current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	2.7~3.6	—	20.0	μA	
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V	2.7~3.6	—	± 20.0		
Increase In I <sub>CC</sub> Per Input		ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V	2.7~3.6	—	750	μA	

**ELECTRICAL CHARACTERISTICS**

DC characteristics (Ta = -40~85°C, 2.3 V ≤ VCC ≤ 2.7 V)

PARAMETER		SYMBOL	TEST CONDITION	VCC (V)	MIN	MAX	UNIT	
Input Voltage	"H" Level	V <sub>IH</sub>		2.3~2.7	1.6	—	V	
	"L" Level	V <sub>IL</sub>		2.3~2.7	—	0.7		
Output Voltage	"H" Level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	2.3~2.7	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -4 mA	2.3	2.0	—	
				I <sub>OH</sub> = -6 mA	2.3	1.8	—	
				I <sub>OH</sub> = -8 mA	2.3	1.7	—	
	"L" Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.3~2.7	—	0.2	
				I <sub>OL</sub> = 6 mA	2.3	—	0.4	
				I <sub>OL</sub> = 8 mA	2.3	—	0.6	
Input Leakage Current		I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6 V	2.3~2.7	—	± 5.0	μA	
3-State Output Off-State Current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~3.6 V	2.3~2.7	—	± 10.0	μA	
Power Off Leakage Current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6 V	0	—	10.0	μA	
Quiescent Supply Current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	2.3~2.7	—	20.0	μA	
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V	2.3~2.7	—	± 20.0		

**ELECTRICAL CHARACTERISTICS**

DC characteristics (Ta = -40~85°C, 1.8 V ≤ VCC < 2.3 V)

PARAMETER		SYMBOL	TEST CONDITION		VCC (V)	MIN	MAX	UNIT
Input Voltage	"H" Level	V <sub>IH</sub>			1.8~2.3	0.7 × V <sub>CC</sub>	—	V
	"L" Level	V <sub>IL</sub>			1.8~2.3	—	0.2 × V <sub>CC</sub>	
Output Voltage	"H" Level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -100 μA	1.8	V <sub>CC</sub> - 0.2	—	V
				I <sub>OH</sub> = -4 mA	1.8	1.4	—	
	"L" Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	1.8	—	0.2	
				I <sub>OL</sub> = 4 mA	1.8	—	0.3	
Input Leakage Current		I <sub>IN</sub>	V <sub>IN</sub> = 0~3.6 V		1.8	—	± 5.0	μA
3-State Output Off-State Current		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0~3.6 V		1.8	—	± 10.0	μA
Power Off Leakage Current		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6 V		0	—	10.0	μA
Quiescent Supply Current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	—	20.0	μA
			V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		1.8	—	± 20.0	

AC characteristics (Ta = -40~85°C, Input  $t_r = t_f = 2.0$  ns,  $C_L = 30$  pF,  $R_L = 500 \Omega$ )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	MIN	MAX	UNIT
Propagation Delay Time (D-Q)	$t_{pLH}$ $t_{pHL}$	(Fig.1, 2)	1.8	1.5	5.8	ns
			$2.5 \pm 0.2$	1.0	4.5	
			$3.3 \pm 0.3$	0.8	3.3	
Propagation Delay Time (LE-Q)	$t_{pLH}$ $t_{pHL}$	(Fig.1, 2)	1.8	1.5	6.2	ns
			$2.5 \pm 0.2$	1.0	4.9	
			$3.3 \pm 0.3$	0.8	3.6	
3-State Output Enable Time	$t_{pZL}$ $t_{pZH}$	(Fig.1, 3)	1.8	1.5	7.6	ns
			$2.5 \pm 0.2$	1.0	5.4	
			$3.3 \pm 0.3$	0.8	3.9	
3-State Output Disable Time	$t_{pLZ}$ $t_{pHZ}$	(Fig.1, 3)	1.8	1.5	5.3	ns
			$2.5 \pm 0.2$	1.0	4.4	
			$3.3 \pm 0.3$	0.8	4.0	
Minimum Pulse Width (LE)	$t_w$ (H)	(Fig.1, 2)	1.8	3.0	—	ns
			$2.5 \pm 0.2$	1.5	—	
			$3.3 \pm 0.3$	1.5	—	
Minimum Set-up Time	$t_s$	(Fig.1, 2)	1.8	2.5	—	ns
			$2.5 \pm 0.2$	1.5	—	
			$3.3 \pm 0.3$	1.5	—	
Minimum Hold Time	$t_h$	(Fig.1, 2)	1.8	1.0	—	ns
			$2.5 \pm 0.2$	1.0	—	
			$3.3 \pm 0.3$	1.0	—	
Output To Output Skew	$t_{osLH}$ $t_{osHL}$	(Note 11)	1.8	—	0.5	ns
			$2.5 \pm 0.2$	—	0.5	
			$3.3 \pm 0.3$	—	0.5	

For  $C_L = 50$  pF, add approximately 300 ps to the AC maximum specification.

(Note 11) : Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic switching characteristics (Ta = 25°C, Input tr = tf = 2.0 ns, CL = 30 pF)

PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	TYP.	UNIT
Quiet Output Maximum Dynamic VOL	VOLP	VIH = 1.8 V, VIL = 0 V (Note 12)	1.8	0.15	V
		VIH = 2.5 V, VIL = 0 V (Note 12)	2.5	0.25	
		VIH = 3.3 V, VIL = 0 V (Note 12)	3.3	0.35	
Quiet Output Minimum Dynamic VOL	VOLV	VIH = 1.8 V, VIL = 0 V (Note 12)	1.8	-0.15	V
		VIH = 2.5 V, VIL = 0 V (Note 12)	2.5	-0.25	
		VIH = 3.3 V, VIL = 0 V (Note 12)	3.3	-0.35	
Quiet Output Minimum Dynamic VOH	VOHV	VIH = 1.8 V, VIL = 0 V (Note 12)	1.8	1.55	V
		VIH = 2.5 V, VIL = 0 V (Note 12)	2.5	2.05	
		VIH = 3.3 V, VIL = 0 V (Note 12)	3.3	2.65	

(Note 12) : Parameter guaranteed by design.

Capacitive characteristics (Ta = 25°C)

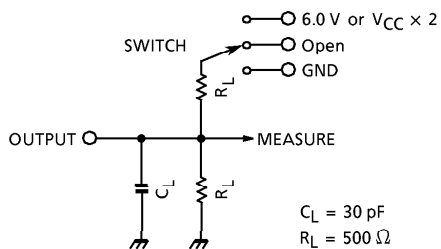
PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	TYP.	UNIT
Input Capacitance	CIN		1.8, 2.5, 3.3	6	pF
Output Capacitance	CO		1.8, 2.5, 3.3	7	pF
Power Dissipation Capacitance	CPD	fIN = 10 MHz (Note 13)	1.8, 2.5, 3.3	20	pF

(Note 13) : CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 16 \text{ (per bit)}$$

**TEST CIRCUIT**  
Fig.1



PARAMETER	SWITCH
$t_{pLH}$ , $t_{pHL}$	Open
$t_{pLZ}$ , $t_{pZL}$	6.0 V @ $V_{CC} = 3.3 \pm 0.3 \text{ V}$ $V_{CC} \times 2$ @ $V_{CC} = 2.5 \pm 0.2 \text{ V}$ @ $V_{CC} = 1.8 \text{ V}$
$t_{pHZ}$ , $t_{pZH}$	GND

**AC WAVEFORM**

Fig.2  $t_{pLH}$ ,  $t_{pHL}$ ,  $t_w$ ,  $t_s$ ,  $t_h$

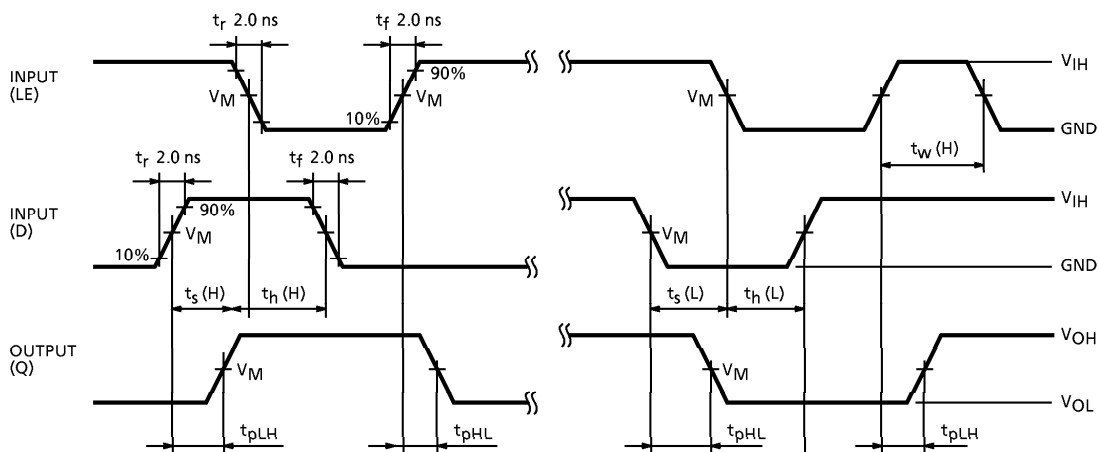
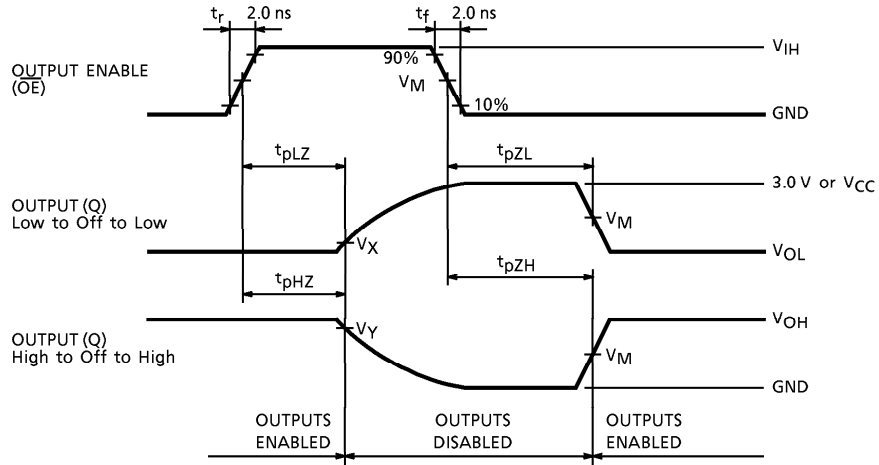




Fig.3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$

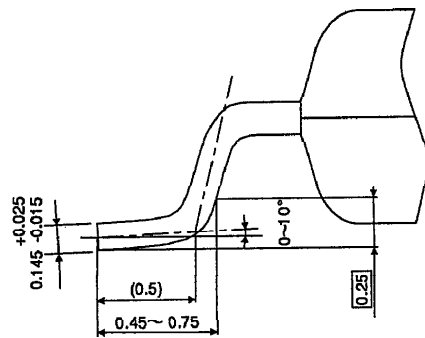
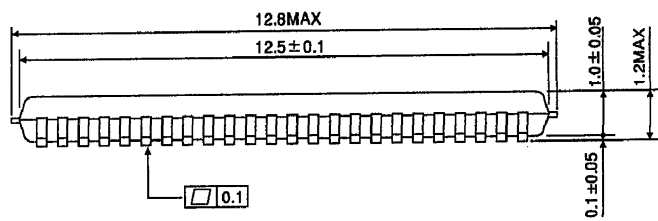
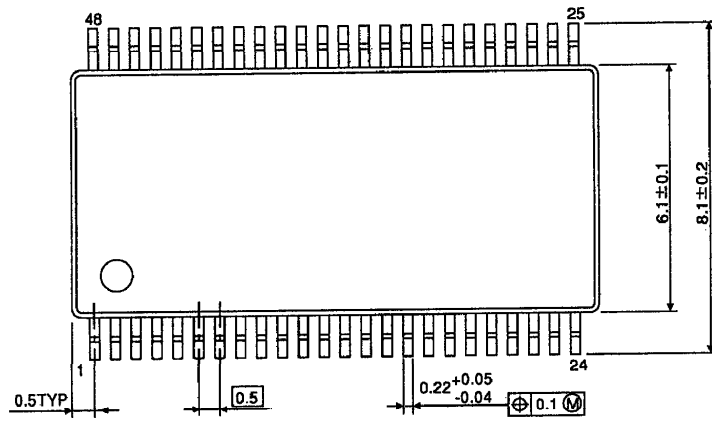


SYMBOL	$V_{CC}$		
	$3.3 \pm 0.3V$	$2.5 \pm 0.2V$	1.8 V
$V_{IH}$	2.7 V	$V_{CC}$	$V_{CC}$
$V_M$	1.5 V	$V_{CC} / 2$	$V_{CC} / 2$
$V_X$	$V_{OL} + 0.3 V$	$V_{OL} + 0.15 V$	$V_{OL} + 0.15 V$
$V_Y$	$V_{OH} - 0.3 V$	$V_{OH} - 0.15 V$	$V_{OH} - 0.15 V$

**OUTLINE DRAWING**

TSSOP48-P-0061-0.50

Unit : mm



Weight : 0.25 g (Typ.)